

Quasi-Continuum Density Functional Theory

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Introduction (QM2CM)

- Problems arising in the study of defective crystals are inherently *multiscale*

- Need to resolve simultaneously:

- *Electronic structure of defect cores*
- *Long-range elastic fields of defects*

- Typical fundamental challenge: Quantum mechanical calculations at macroscopic scales!

- *Vacancies*
- *Dislocations*
- *Domain walls: cell size $\sim 1 \mu\text{m}$*
- *Grain boundaries: cell size $\sim 20 \mu\text{m}$*

- Physically relevant cell sizes are far larger than can be analyzed by conventional computational chemistry
- Need to coarse-grain quantum mechanics!



Orbital-Free Density Functional Theory

- Total energy functional: $E[\rho] = T_s[\rho] + E_{xc}[\rho]$

$$+ \frac{1}{2} \int_{\Omega} \int_{\Omega} \frac{\rho(\mathbf{r})\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r} d\mathbf{r}' + \int \rho(\mathbf{r})v(\mathbf{r}) d\mathbf{r}$$

- Thomas-Fermi-Weizsacker (TF-λW) KE:

$$T_s(\rho) \approx \frac{3}{10}(3\pi^2)^{2/3} \int \rho^{5/3}(\mathbf{r}) d\mathbf{r} + \frac{\lambda}{8} \int \frac{|\nabla \rho(\mathbf{r})|^2}{\rho(\mathbf{r})} d\mathbf{r}$$

- Exchange-correlation energy (LDA):

$$E_{xc}[\rho] \approx \int \epsilon_c(\rho)\rho(\mathbf{r}) d\mathbf{r} - \frac{3}{4} \left(\frac{3}{\pi}\right)^{1/3} \int \rho^{4/3}(\mathbf{r}) d\mathbf{r}$$



Orbital-Free Density Functional Theory

- Total energy functional:

$$E[\rho, \mathbf{R}] = \int \epsilon_{loc}(\mathbf{r}, \rho, \nabla \rho) d\mathbf{r} + \frac{1}{2} \int \int \frac{\rho(\mathbf{r})\rho(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r} d\mathbf{r}'$$

*'Garden-variety' functionals
amenable to standard finite-
element discretization!*

- Local energy functional

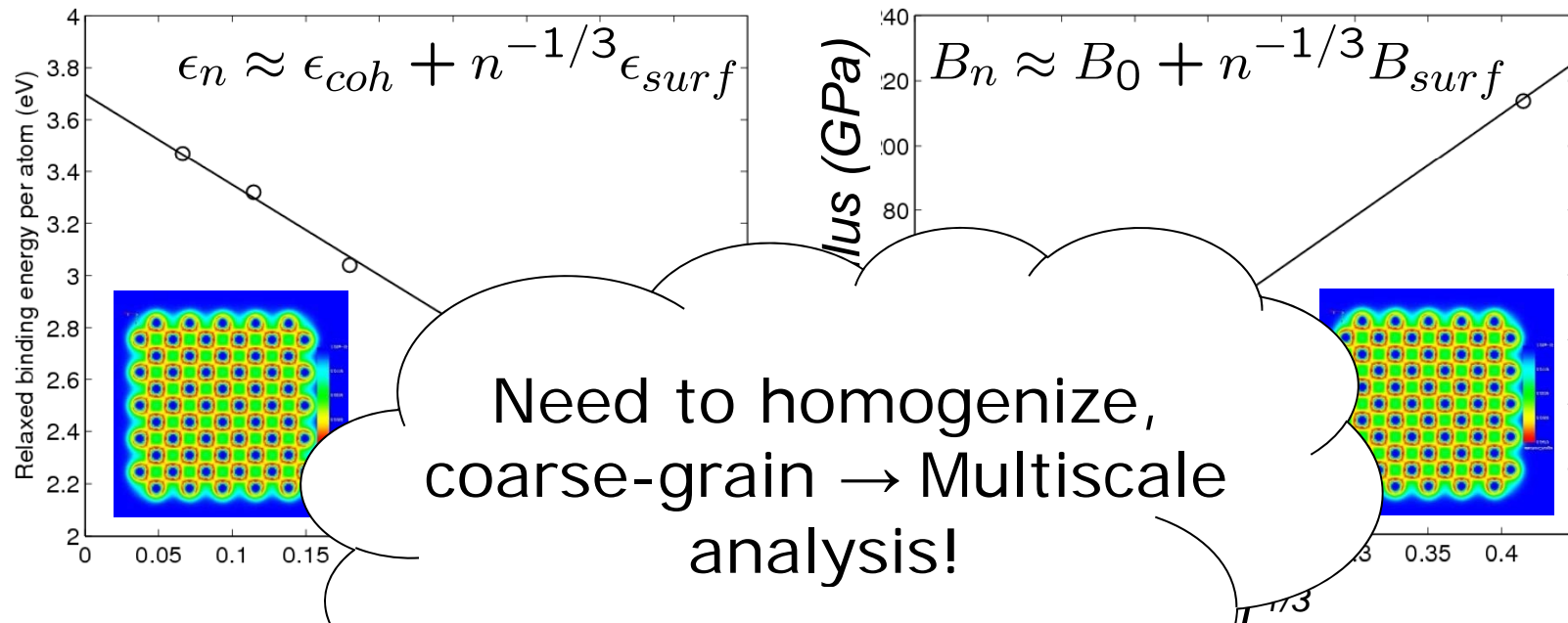
$$L[\rho, \phi, \mathbf{R}] = \int_{\mathbb{R}^3} \epsilon_{loc}(\mathbf{r}, \rho, \nabla \phi) d\mathbf{r} - \frac{1}{8\pi} \int_{\Omega} |\nabla \phi(\mathbf{r})|^2 d\mathbf{r} + \int_{\Omega} (\rho(\mathbf{r}) + \underbrace{b(\mathbf{r})}_{\text{pseudopotentials}}) \phi(\mathbf{r}) d\mathbf{r}$$



pseudopotentials

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OFDFT – Coarse-graining

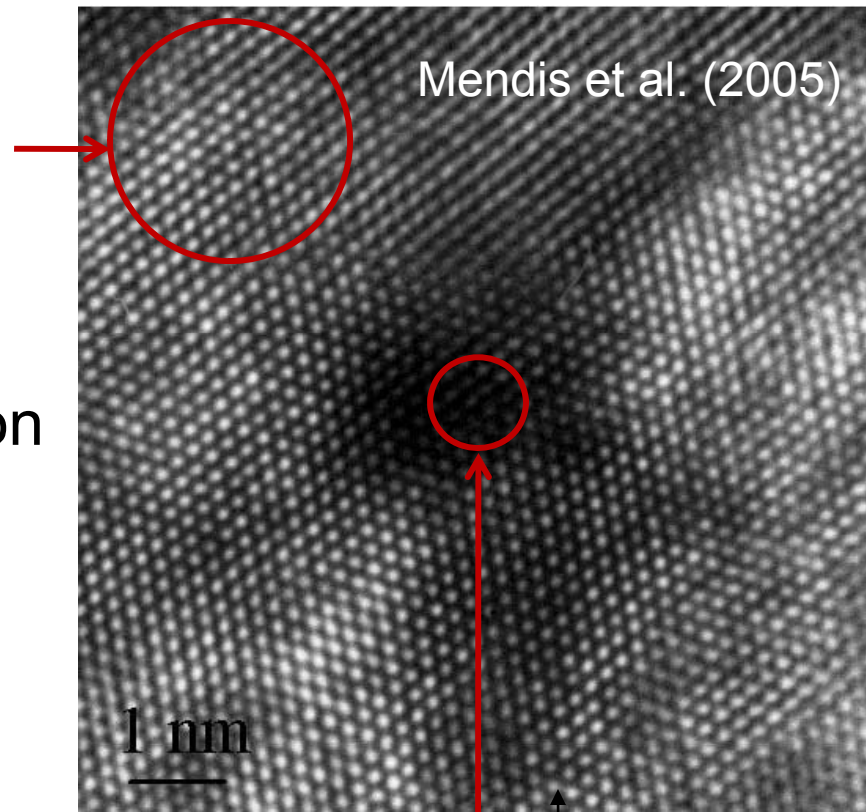


- Real-space formulation, finite-element approximation
→ Nonperiodic, unstructured, OFDFT calculations
- However, calculations are still expensive:
9x9x9 cluster = 3730 atoms required 10,000 CPU hours!

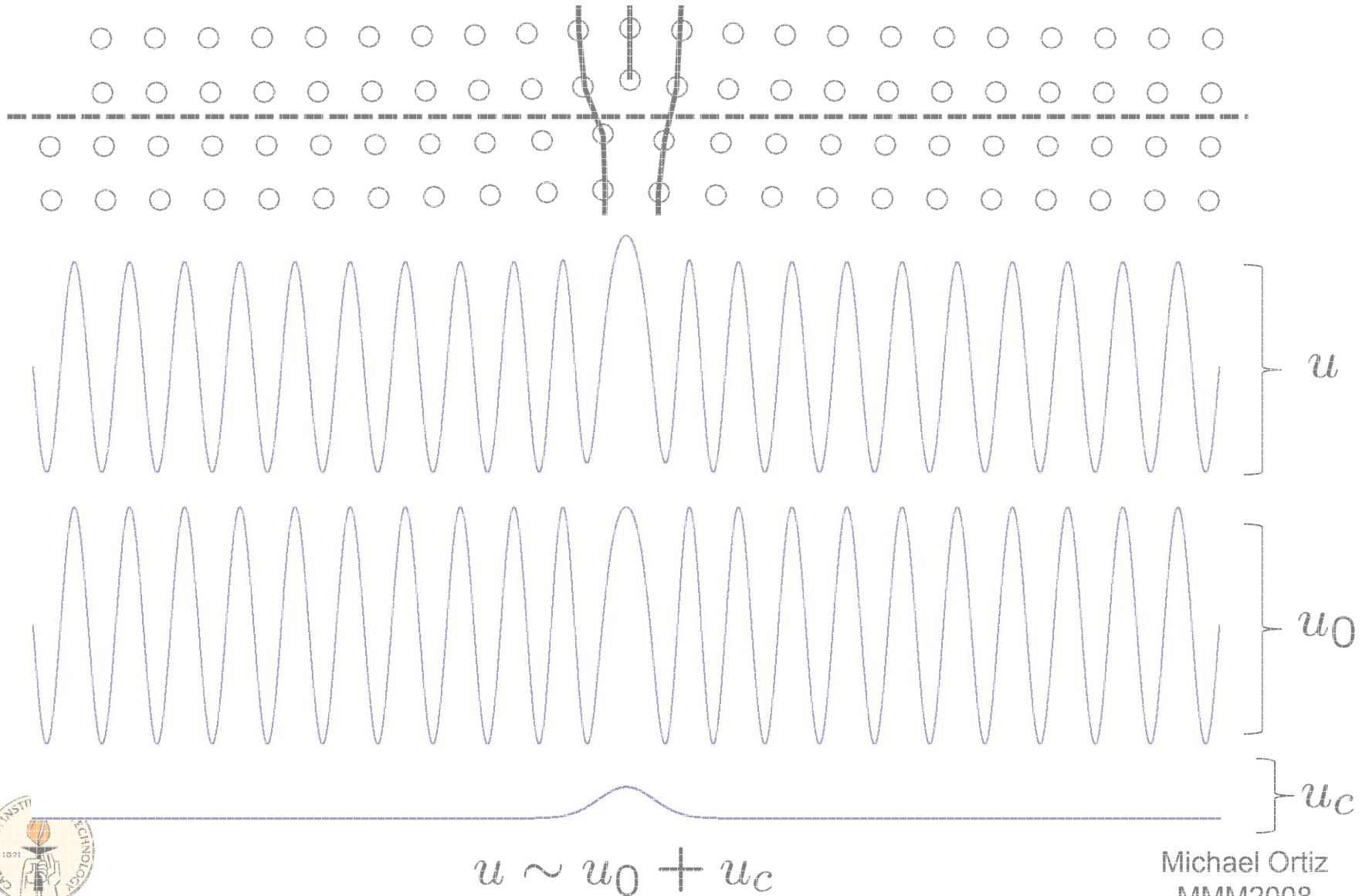


Defective crystals – The bridge

- Away from defects, atoms 'see' the electron density of a uniformly distorted periodic lattice: Cauchy-Born electron density + slowly varying modulation (Blanc, Le Bris and Lions, ARMA, 2002)
- Only near defect cores the electron density and the electrostatic potential deviate significantly from those of a periodic lattice

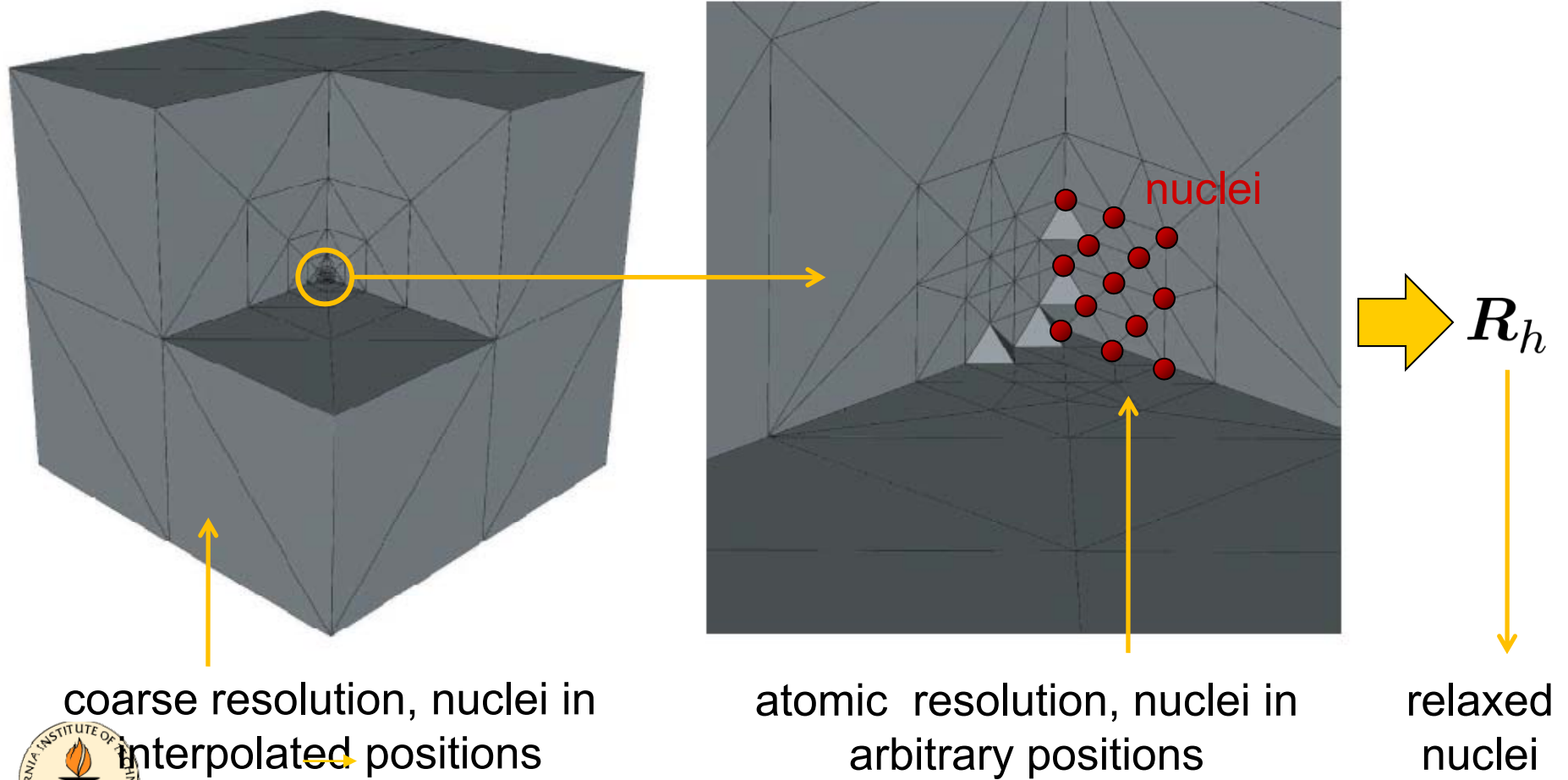


Defective crystals – The bridge



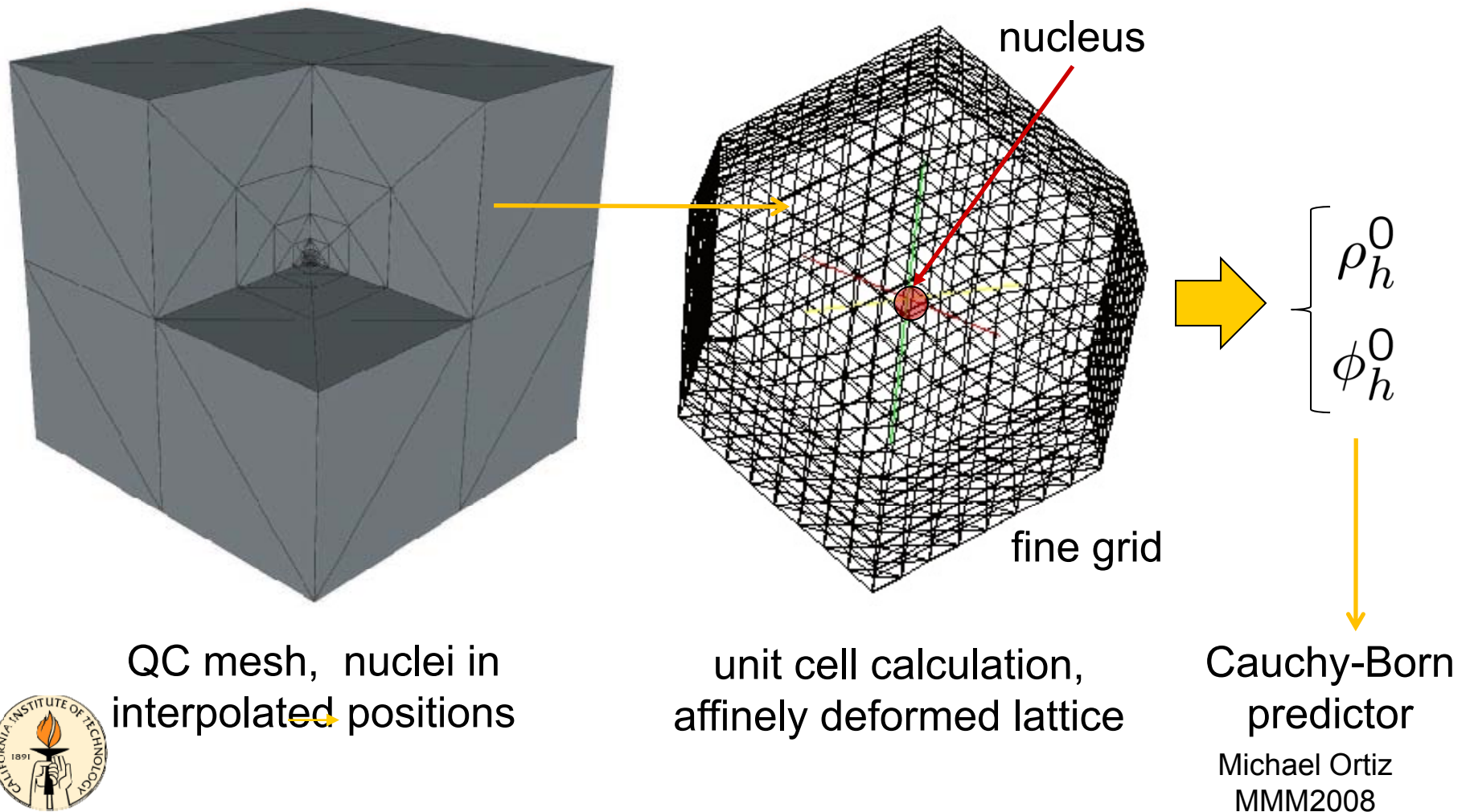
QC/OFDFT – Multiscale hierarchy

- Quasi-continuum: $\mathbf{R} \rightarrow \mathbf{R}_h \in \mathbb{R}^{3N_h}$, $N_h \ll N$



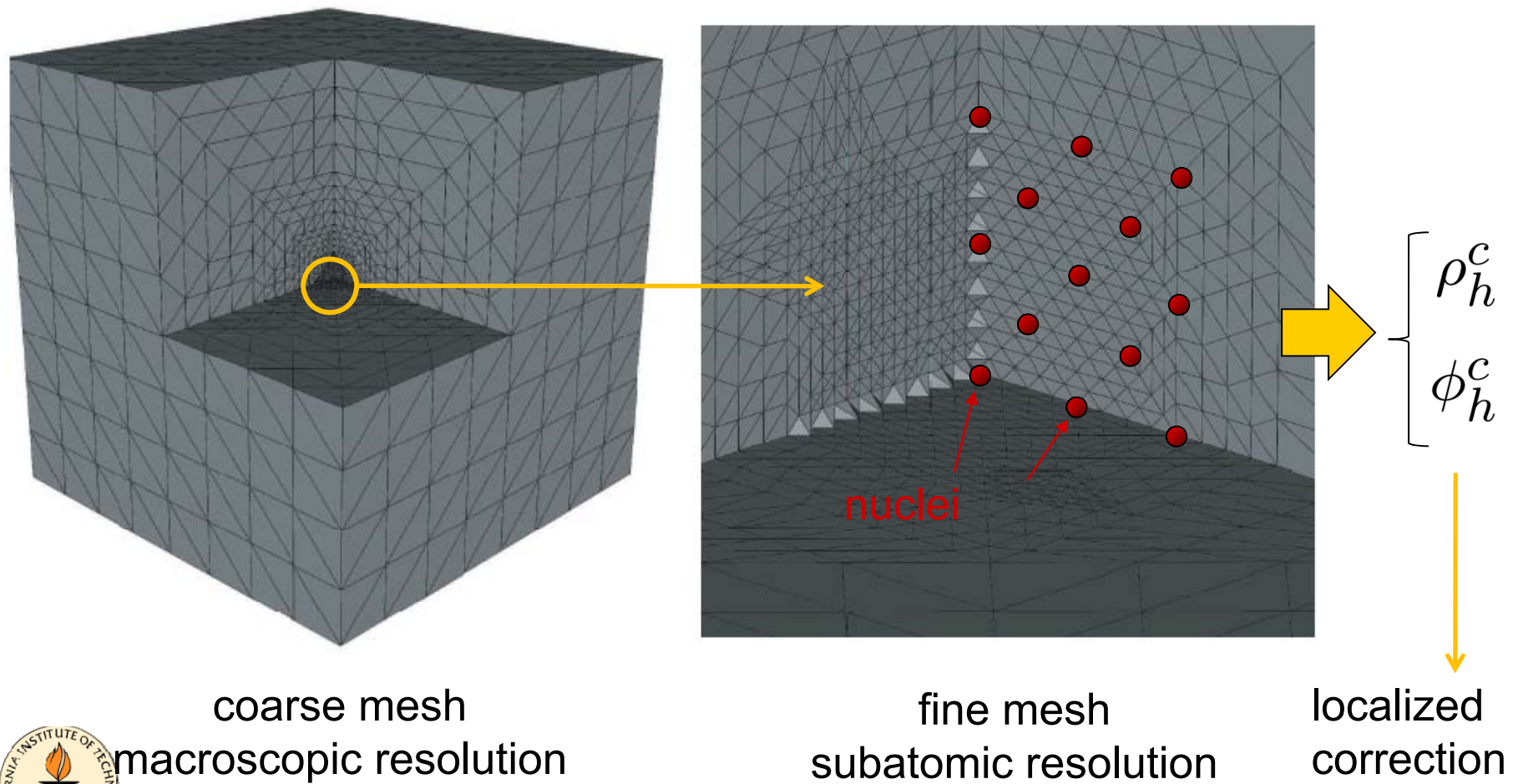
QC/OFDFT – Multiscale hierarchy

- Each element represents affinely deformed lattice



QC/OFDFT – Multiscale hierarchy

- Localized correction to Cauchy-Born predictor:



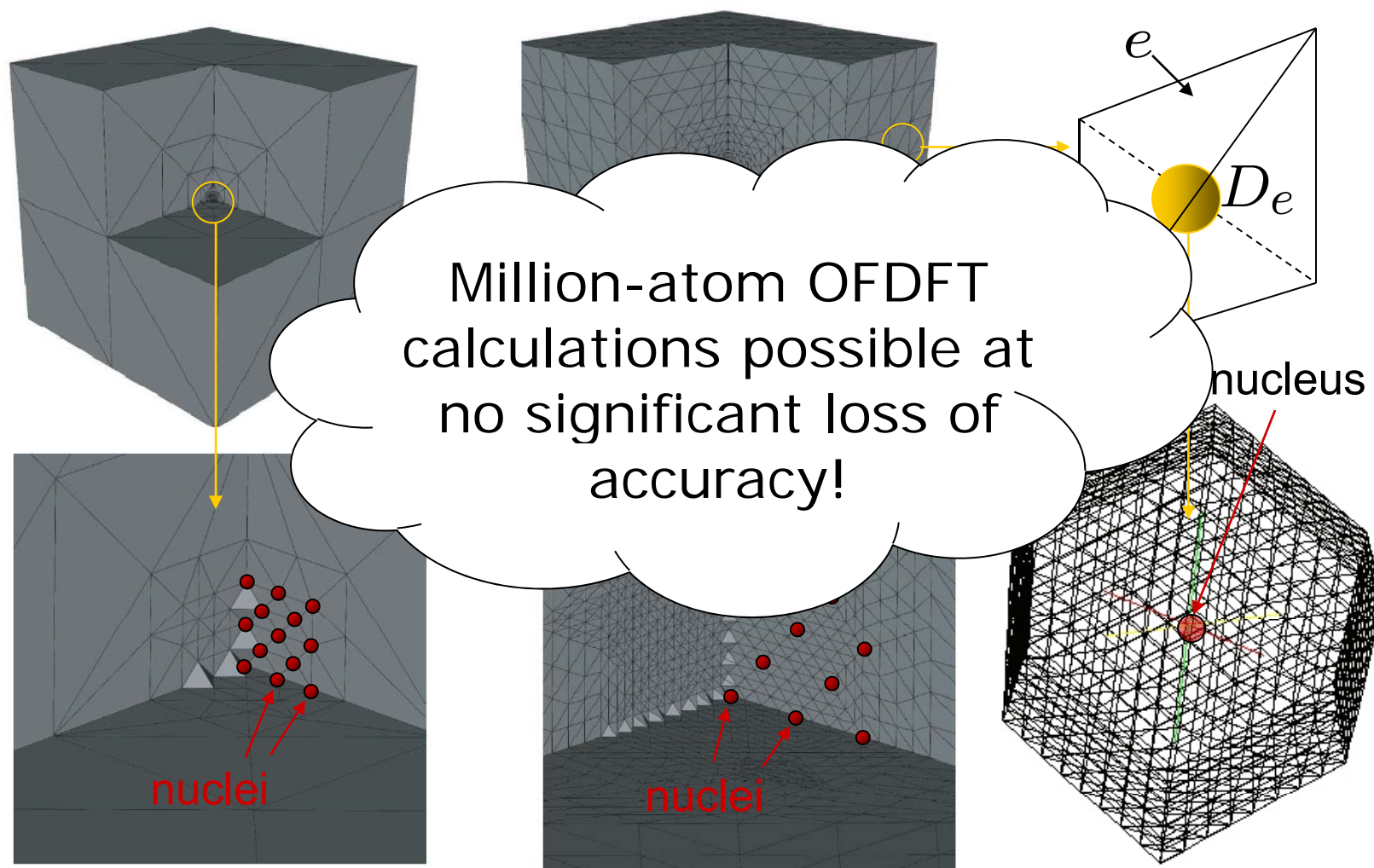
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QC/OFDFT – Multiscale hierarchy

Quasi-continuum

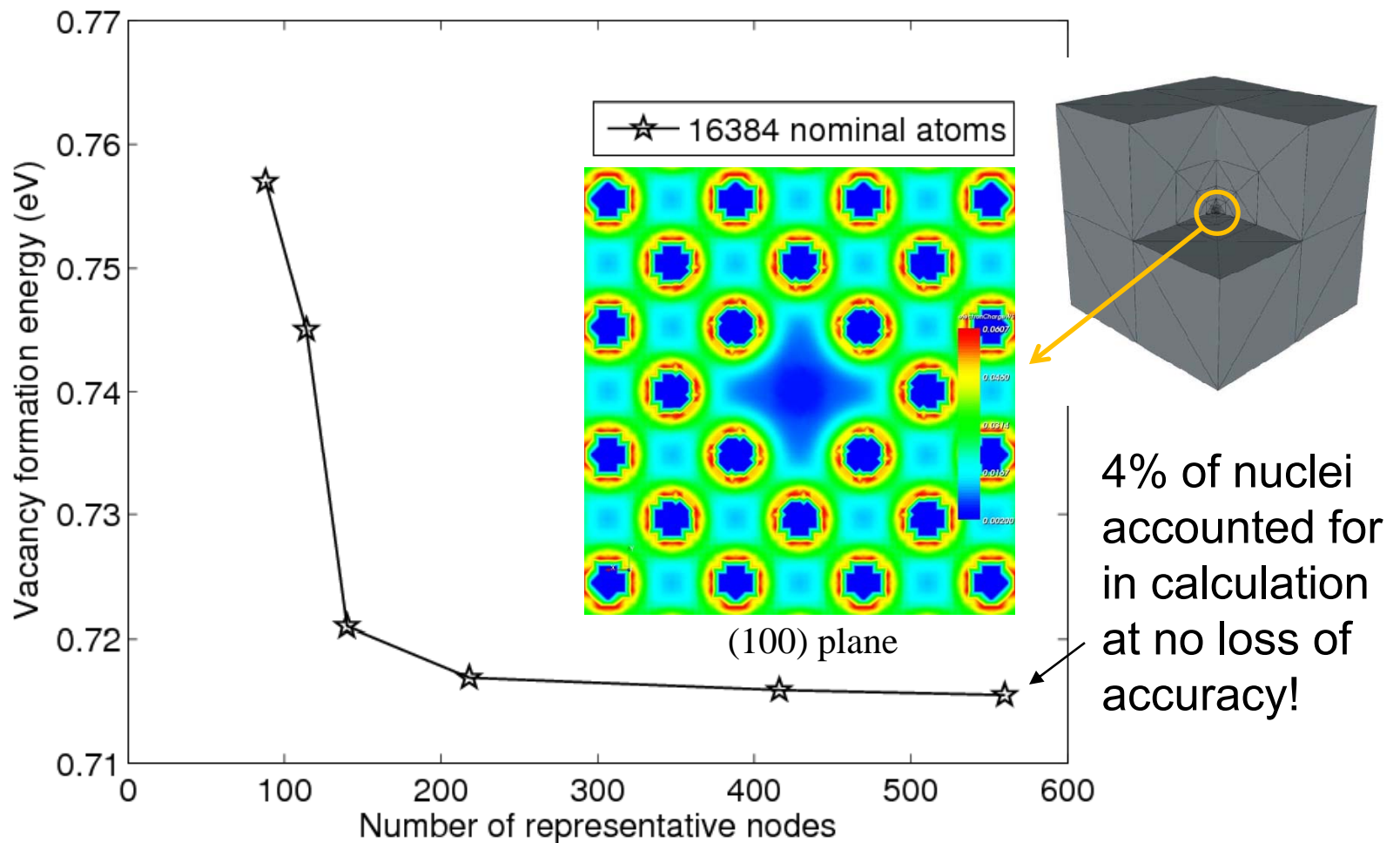
Corrector

Predictor/Quadrature



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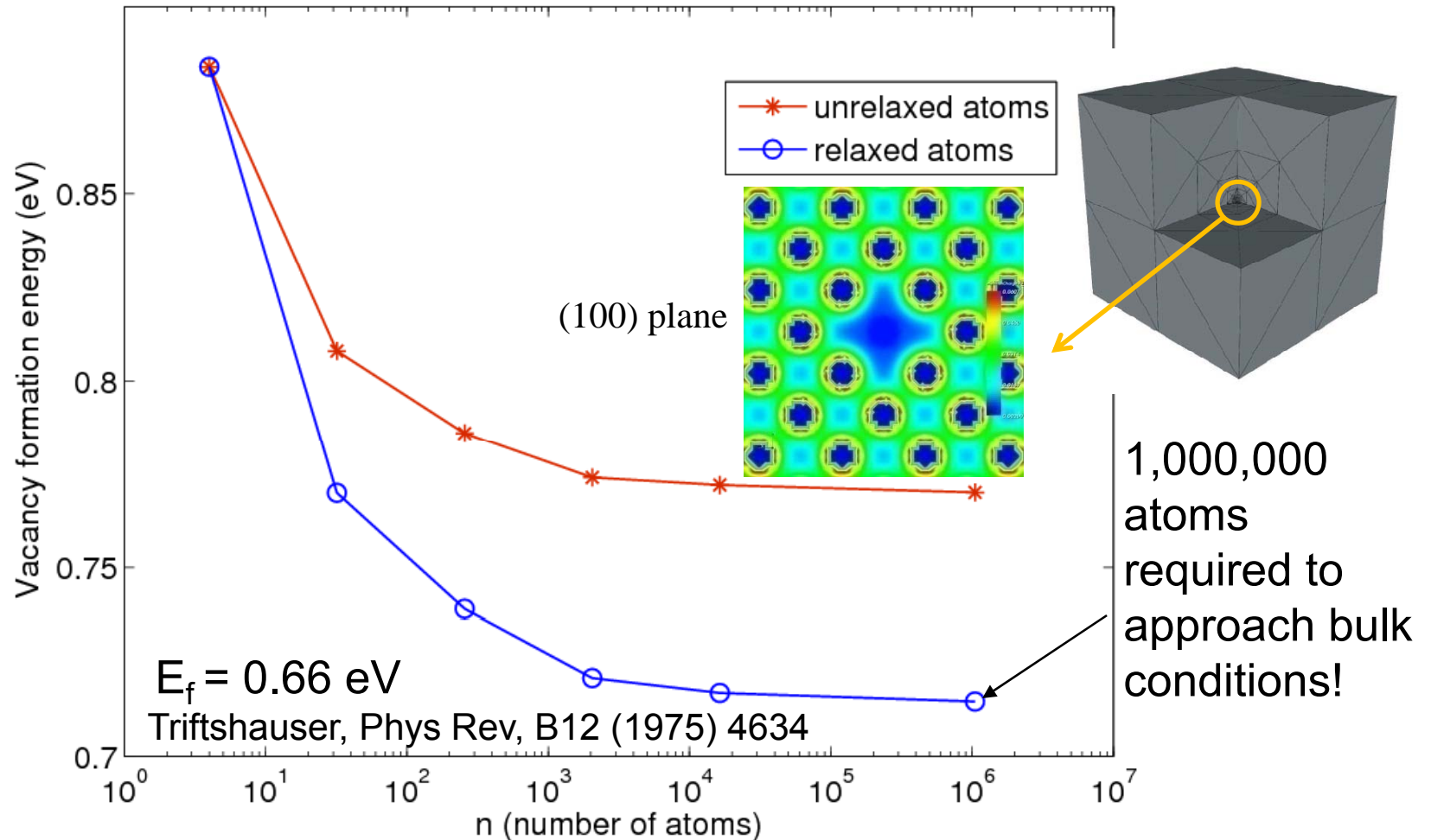
QC/OFDFT convergence – Al vacancy



Convergence of multiscale scheme

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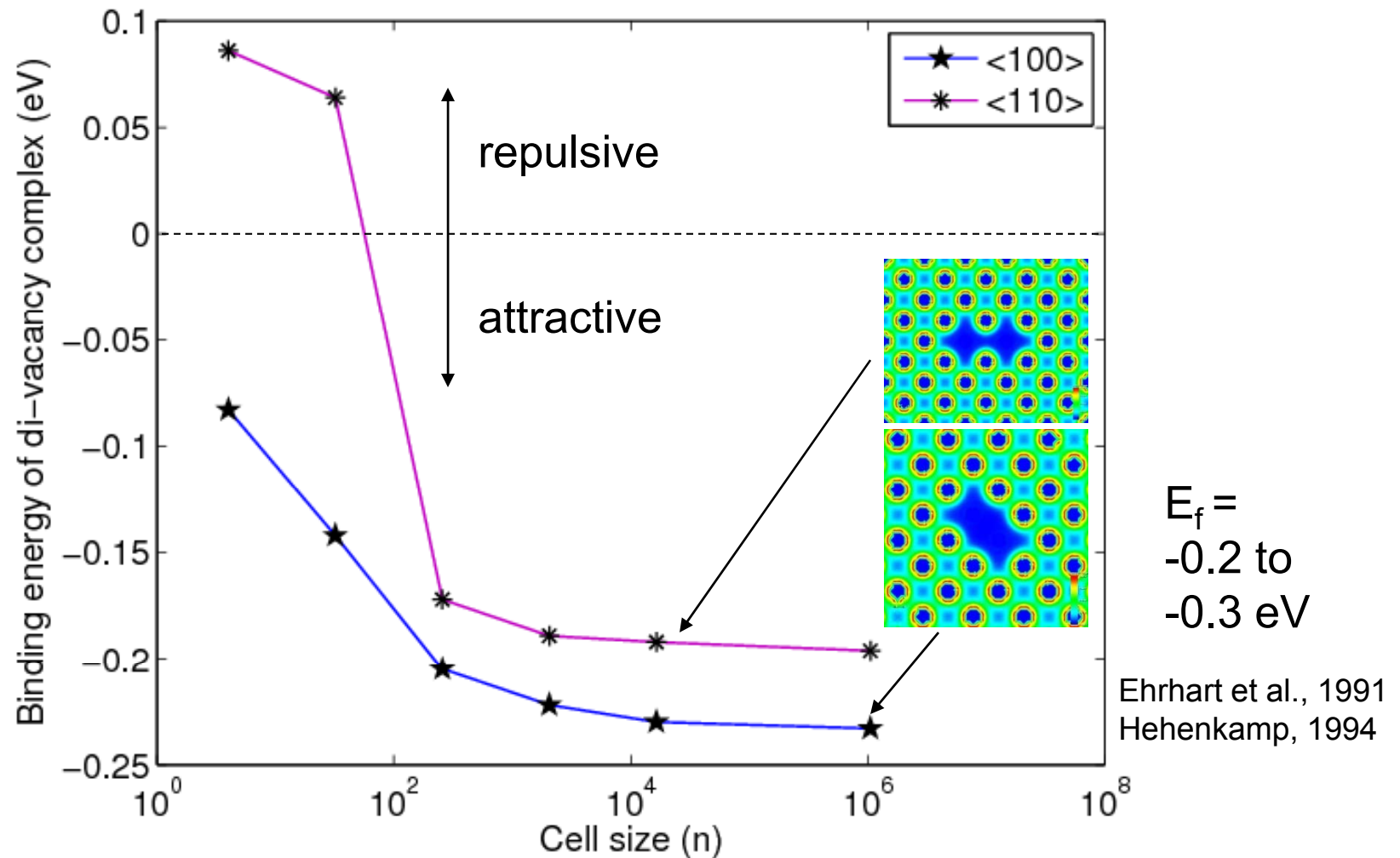
Cell-size dependence – Al vacancy



Convergence with material sample size

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Case study 1 – Di-vacancies in Al

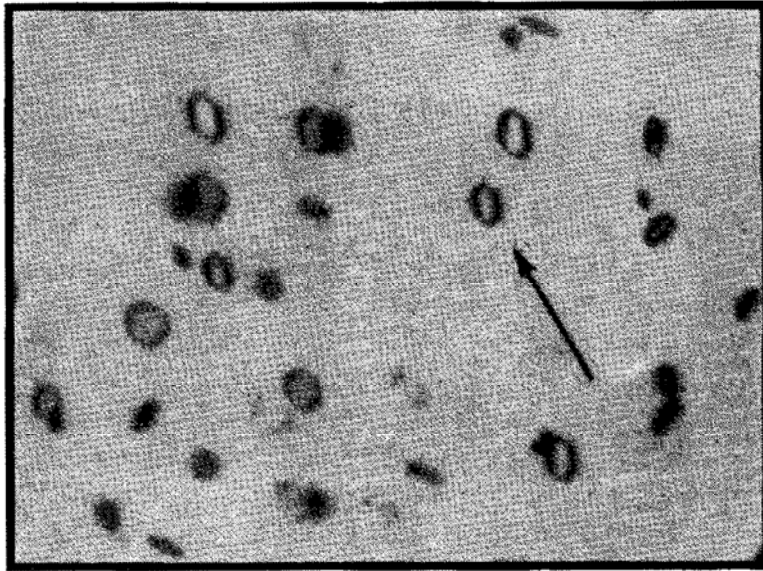


Binding energy vs. material sample size

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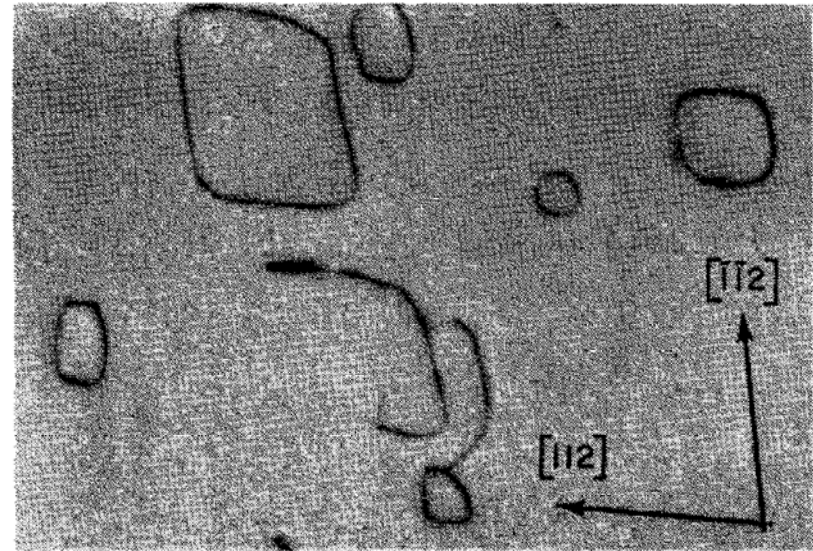


Case study 2 – Prismatic loops in Al



Prismatic dislocation loops formed by condensation of vacancies in quenched aluminum

Kulmann-Wilsdorff and Kuhlmann,
J. Appl. Phys., **31** (1960) 516.



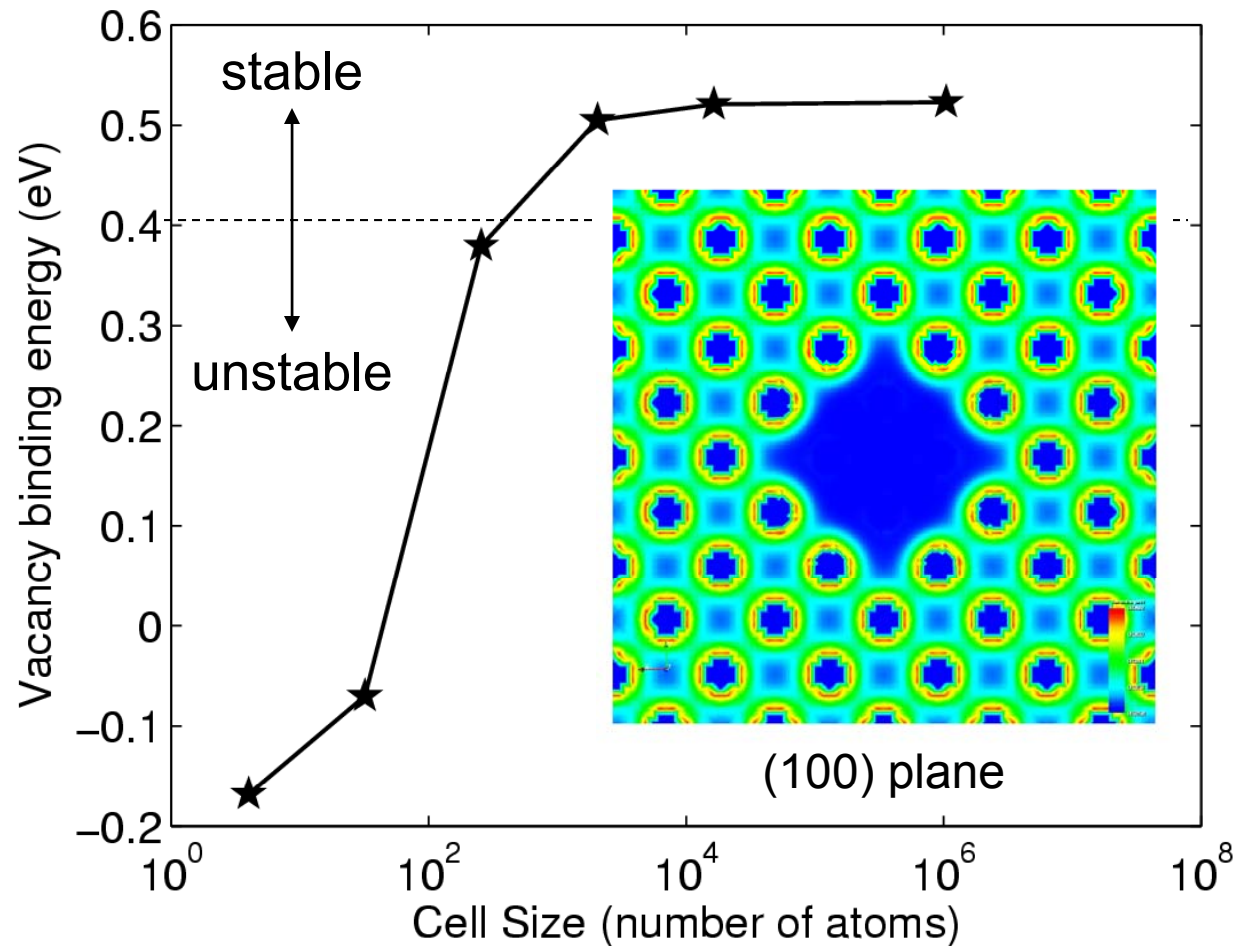
Prismatic dislocation loops formed by condensation of vacancies in quenched Al-05%Mg

Takamura and Greensfield,
J. Appl. Phys., **33** (1961) 247.

- Prismatic dislocation loops also in irradiated materials
- Loops smaller than 50 nm undetectable: Nucleation mechanism? Vacancy condensation?



Case study 2 – Prismatic loops in Al



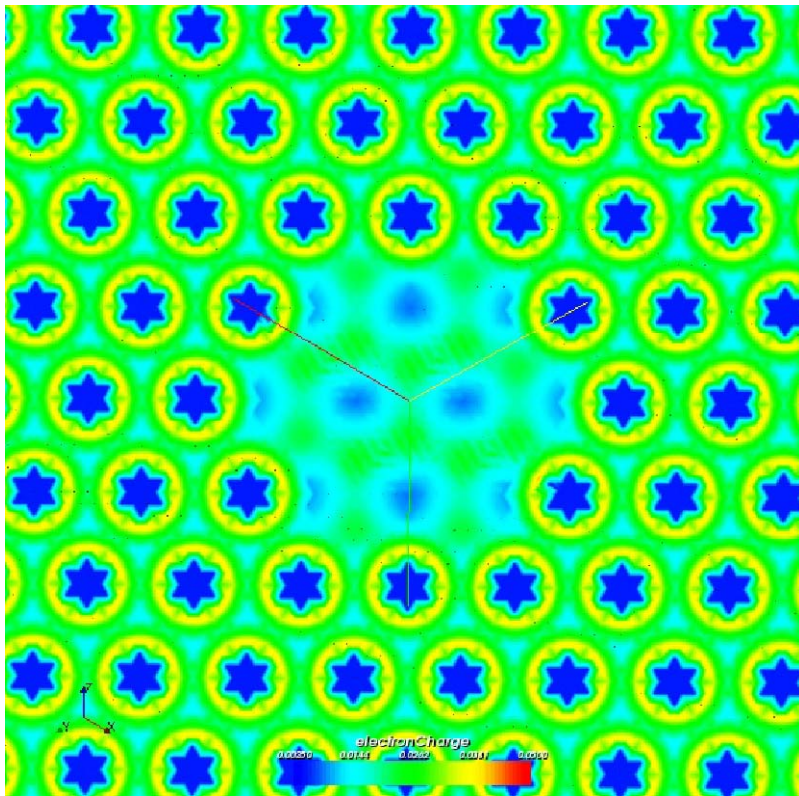
Quad-vacancy binding energy vs. material sample size



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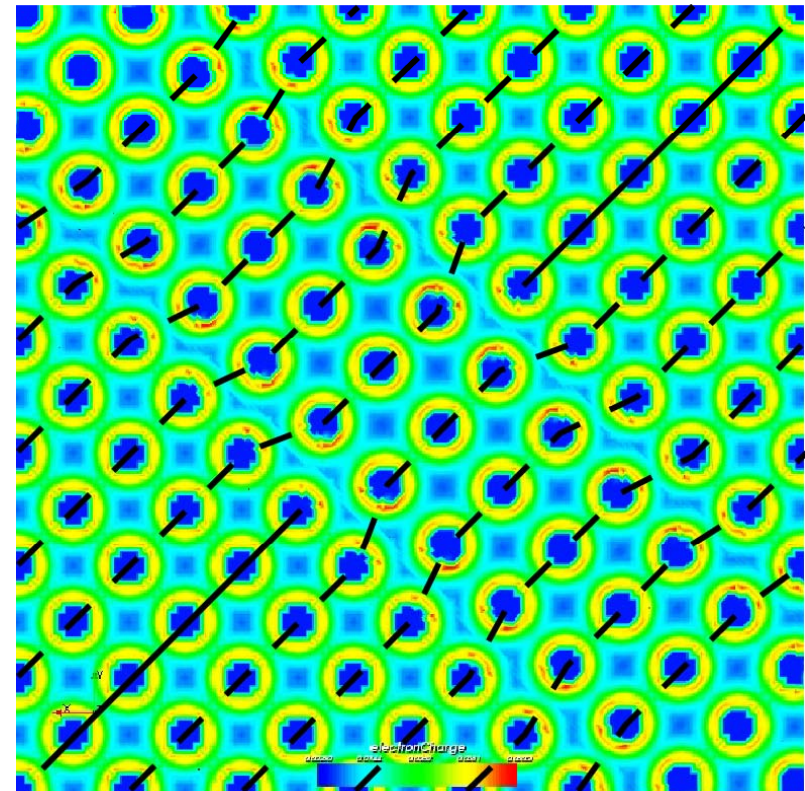
Case study 2 – Prismatic loops in Al

(111)



Non-collapsed configuration
Binding energy = -0.88 eV

(001)



$1/2\langle 110 \rangle$ prismatic loop
Binding energy = -1.57 eV

(111)

Stability of hepta-vacancy



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Concluding remarks

- Behavior of material samples may change radically with size (concentration): Small samples may not be representative of bulk behavior
- Need electronic structure calculations at macroscopic scales: Quasi-continuum OFDFT (QC/OFDFT)
- Outlook: Application to general materials requires extension to Kohn-Sham DFT...

